

# Hyperfast Rectifier, 1 A FRED Pt®



SMA (DO-214AC)



## FEATURES

- Hyperfast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	1 A
$V_R$	1200 V
$V_F$ at $I_F$	1.10 V
$t_{rr}$	75 ns
$T_J$ max.	175 °C
Package	SMA (DO-214AC)
Circuit configuration	Single

## DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use as clamp, snubber and freewheeling diode in a flyback aux power supplies, bootstrap and desaturate for HV MOSFET and IGBT driver, high frequency rectifiers in a cuk and sepic circuit for LED lighting.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

## MECHANICAL DATA

**Case:** SMA (DO-214AC)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002

**Polarity:** color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		1200	V
Average rectified forward current	$I_{F(AV)}$	$T_{Sp} = 144\text{ °C}$ , $D = 0.5$	1	A
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$ , 8.3 ms sine pulse	21	
Operating junction and storage temperatures	$T_J$ , $T_{Stg}$		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_R$	$I_R = 100\text{ }\mu\text{A}$	1200	-	-	V
Forward voltage, per diode	$V_F$	$I_F = 1\text{ A}$	-	1.35	1.80	
		$I_F = 1\text{ A}$ , $T_J = 125\text{ °C}$	-	1.17	1.55	
		$I_F = 1\text{ A}$ , $T_J = 150\text{ °C}$	-	1.10	1.44	
Reverse leakage current, per diode	$I_R$	$V_R = V_R$ rated	-	-	5	$\mu\text{A}$
		$T_J = 150\text{ °C}$ , $V_R = V_R$ rated	-	-	50	
Junction capacitance	$C_T$	$V_R = 1200\text{ V}$	-	3.5	-	pF

**DYNAMIC RECOVERY CHARACTERISTICS** ( $T_J = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$	-	-	75	ns
		$T_J = 25\text{ }^{\circ}\text{C}$	-	99	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	137	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	3.5	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	4.5	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^{\circ}\text{C}$	-	150	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	286	-	

**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^{\circ}\text{C}$
Thermal resistance, junction to mount	$R_{thJM}^{(1)}$	Device mounted on PCB with 2 x 3.5 mm soldering lands	-	15	18	$^{\circ}\text{C/W}$
Thermal resistance, junction to ambient	$R_{thJA}$	Device mounted on PCB with recommended pad size	-	110	-	$^{\circ}\text{C/W}$
Approximate weight			0.07			g
Marking device		Case style SMA (DO-214AC)	1H12			

**Note**

(1) Thermal resistance junction to mount follows JEDEC® 51-14 transient dual interface test method (TDIM)

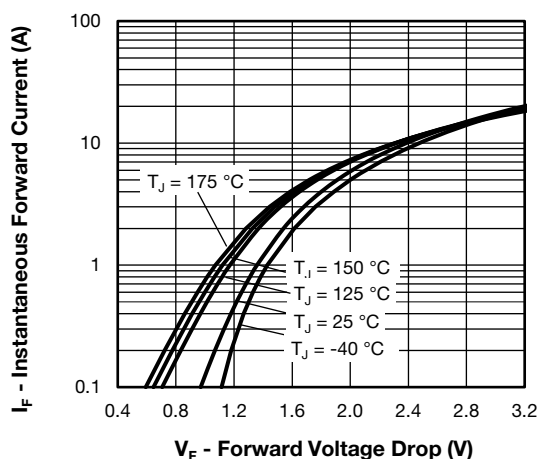


Fig. 1 - Typical Forward Voltage Drop Characteristics

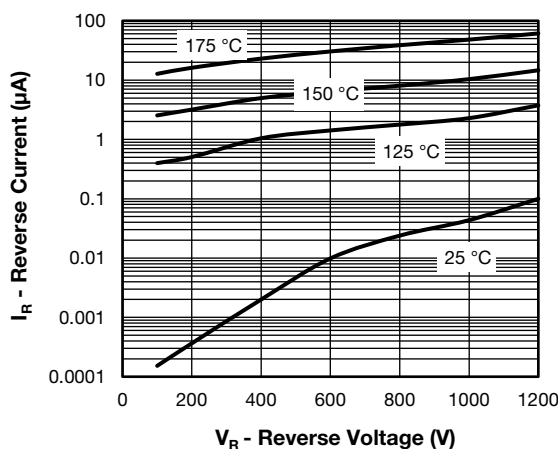


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

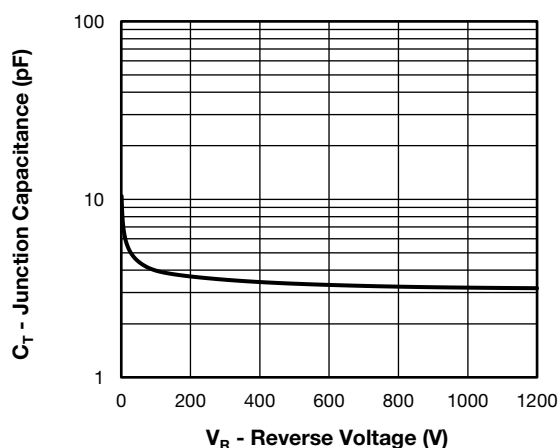


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

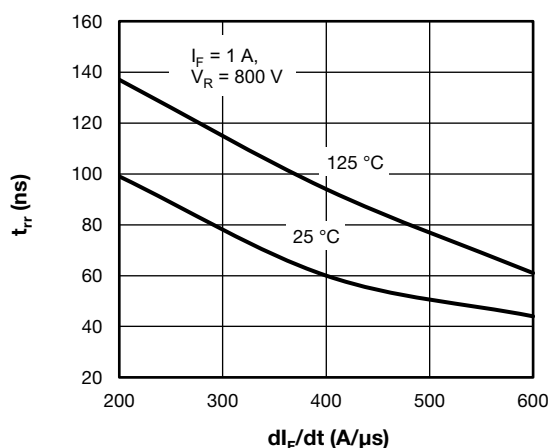
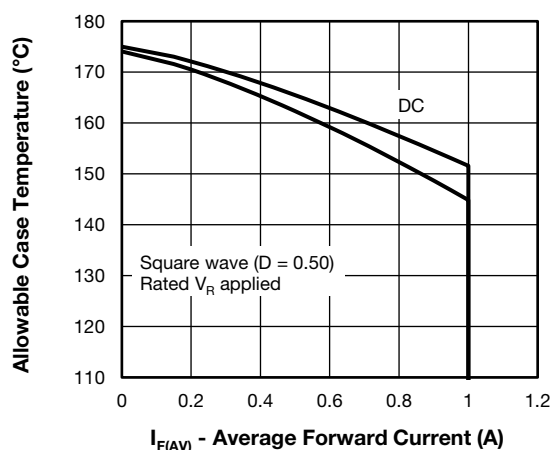

Fig. 6 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

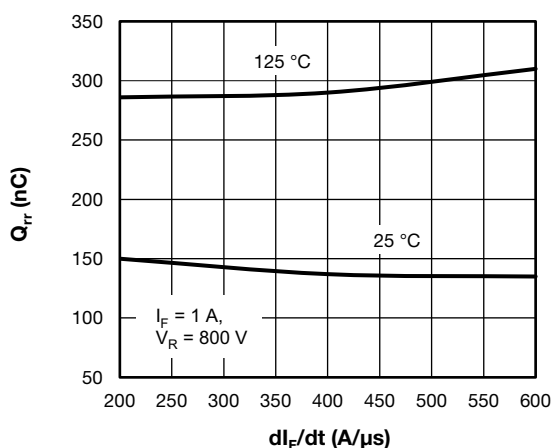
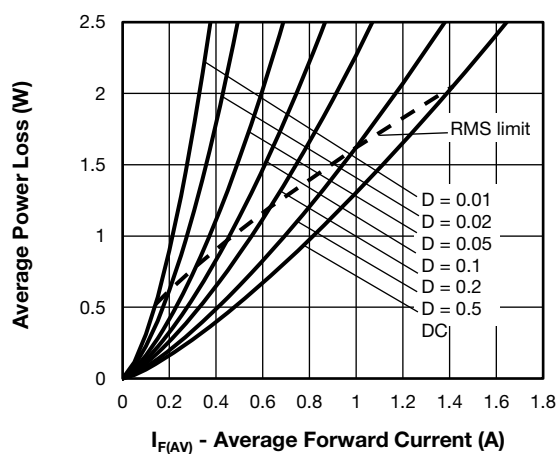
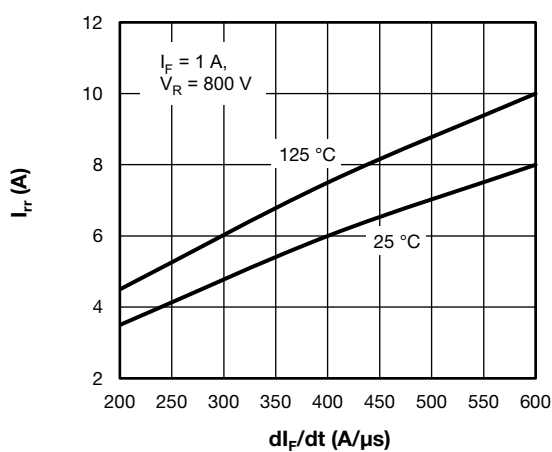

Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$ 


Fig. 5 - Forward Power Loss Characteristics


Fig. 8 -  $I_{rr}$  (A) vs.  $dI_F/dt$ 

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_{rr} (1 - D)$ ;  $I_{rr}$  at  $V_{R1}$  = rated  $V_R$

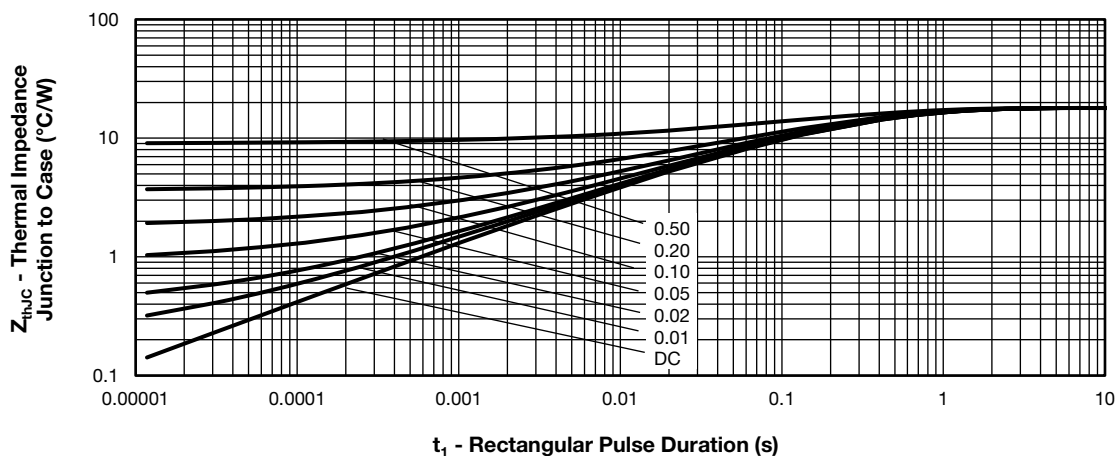


Fig. 9 - Transient Thermal Impedance, Junction to Case

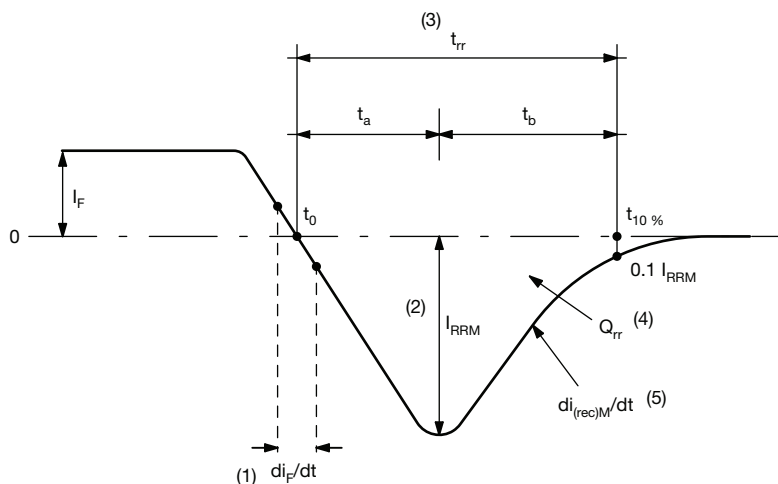


Fig. 10 - Reverse Recovery Waveform and Definitions

#### Notes

- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from  $t_0$ , crossing point of negative going  $I_F$ , to point  $t_{10\%}$ ,  $0.1 I_{RRM}$
- (4)  $Q_{rr}$  - area under curve defined by  $t_0$  and  $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

- (5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

**ORDERING INFORMATION TABLE**

Device code	<b>VS-</b>	<b>E</b>	<b>7</b>	<b>M</b>	<b>H</b>	<b>01</b>	<b>12</b>	<b>H</b>	<b>M3</b>
	1	2	3	4	5	6	7	8	9

- |          |  |
|----------|--|
| <b>1</b> | - Vishay Semiconductors product                                      |
| <b>2</b> | - Circuit configuration:<br>E = single diode                         |
| <b>3</b> | - 7 = FRED generation 7  |
| <b>4</b> | - M = SMA package  |
| <b>5</b> | - Process type,<br>H = hyperfast recovery                            |
| <b>6</b> | - Current rating (01 = 1 A)  |
| <b>7</b> | - Voltage code (12 = 1200 V)   |
| <b>8</b> | - H = AEC-Q101 qualified   |
| <b>9</b> | - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free |

**ORDERING INFORMATION** (Example)

PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-E7MH0112HM3/I	7500	7500	13" diameter plastic tape and reel

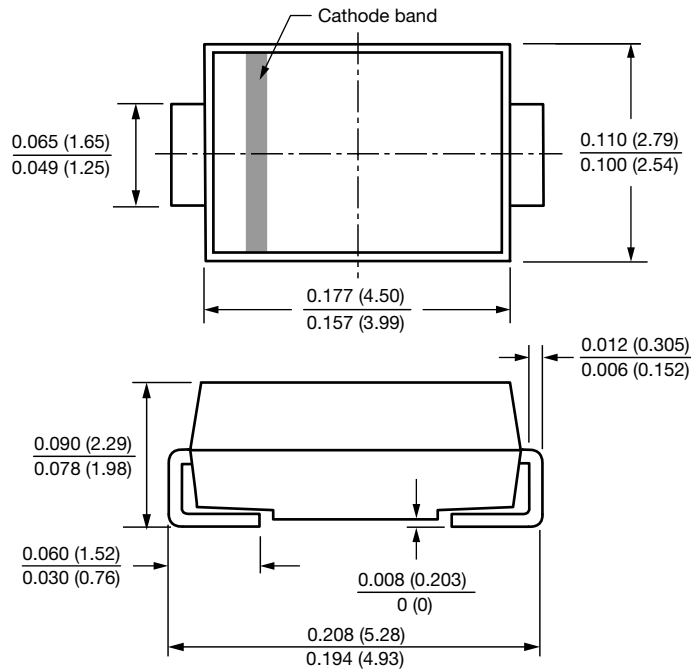
**LINKS TO RELATED DOCUMENTS**

Dimensions	<a href="http://www.vishay.com/doc?95400">www.vishay.com/doc?95400</a>
Part marking information	<a href="http://www.vishay.com/doc?95472">www.vishay.com/doc?95472</a>
Packaging information	<a href="http://www.vishay.com/doc?95404">www.vishay.com/doc?95404</a>
SPICE model	<a href="http://www.vishay.com/doc?97060">www.vishay.com/doc?97060</a>

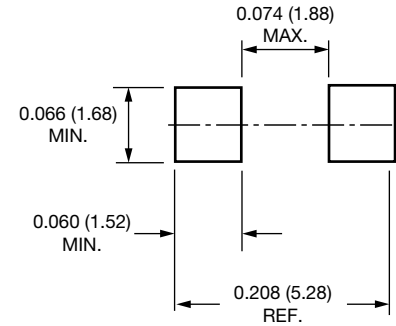
## SMA

**DIMENSIONS** in inches (millimeters)

**DO-214AC (SMA)**



**Mounting Pad Layout**





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